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$Cs_2Bi(PO_4)(WO_4)$

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Key indicators: single-crystal X-ray study; T = 293 K; mean σ (W–O) = 0.009 Å; R factor = 0.052; wR factor = 0.115; data-to-parameter ratio = 22.9.

Dicaesium bismuth(III) phosphate(V) tungstate(VI), Cs₂Bi-(PO₄)(WO₄), has been synthesized during complex investigation in a molten pseudo-quaternary Cs₂O–Bi₂O₃–P₂O₅–WO₃ system. It is isotypic with K₂Bi(PO₄)(WO₄). The threedimensional framework is built up from [Bi(PO₄)(WO₄)] nets, which are organized by adhesion of [BiPO₄] layers and [WO₄] tetrahedra above and below of those layers. The interstitial space is occupied by Cs atoms. Bi, W and P atoms lie on crystallographic twofold axes.

Related literature

For the isotypic potassium analogue, see: Zatovsky *et al.* (2006). For a related structure, see: Terebilenko *et al.* (2008). For caesium coordination, see Borel *et al.* (2000); Yakubovich *et al.* (2006)

Experimental

Crystal data

 $Cs_2Bi(PO_4)(WO_4)$ $M_r = 817.61$ Orthorhombic, *Ibca* a = 21.3144 (10) Å b = 12.6352 (5) Å c = 7.1412 (3) Å

Data collection

Oxford Diffraction XCalibur-3 diffractometer Absorption correction: multi-scan (Blessing, 1995) $T_{min} = 0.061, T_{max} = 0.174$ (expected range = 0.053-0.151) $V = 1923.21 (14) Å^{3}$ Z = 8 Mo K\alpha radiation \mu = 37.87 mm^{-1} T = 293 K 0.08 \times 0.07 \times 0.05 mm

10697 measured reflections 1396 independent reflections 1227 reflections with $I > 2\sigma(I)$ $R_{\text{int}} = 0.156$ Refinement

 $R[F^2 > 2\sigma(F^2)] = 0.052$ $wR(F^2) = 0.115$ S = 1.211396 reflections 61 parameters $\Delta \rho_{\text{max}} = 2.17 \text{ e } \text{ Å}^{-3}$ $\Delta \rho_{\text{min}} = -2.63 \text{ e } \text{ Å}^{-3}$

Table 1Selected bond lengths (Å).

Bi1-O2	2.388 (8)	Cs1-O4 ^{vii}	3.140 (9)
Bi1-O1 ⁱ	2.389 (8)	Cs1-O1	3.338 (9)
Bi1-O3 ⁱⁱ	2.463 (8)	Cs1-O3 ^{vii}	3.339 (9)
Bi1-O1 ⁱⁱⁱ	2.669 (8)	W1-O4	1.774 (9)
Cs1-O2 ⁱⁱ	2.990 (8)	W1-O3 ^{vi}	1.792 (9)
Cs1-O4 ^{iv}	3.031 (9)	P1-O1	1.539 (8)
$Cs1 - O2^i$	3.046 (8)	P1-O1 ⁱⁱ	1.539 (8)
Cs1-O3 ^v	3.088 (9)	$P1-O2^{ii}$	1.549 (8)
$Cs1-O4^{vi}$	3.111 (10)		
	1 2	1	

Symmetry codes: (i) $-x + \frac{1}{2}, -y + \frac{3}{2}, -z + \frac{1}{2}$; (ii) $-x + \frac{1}{2}, y, -z$; (iii) $x, y - \frac{1}{2}, -z$; (iv) $-x, y + \frac{1}{2}, -z + \frac{1}{2}$; (v) $x, -y + \frac{3}{2}, z + \frac{1}{2}$; (vi) $x, -y + 1, -z + \frac{1}{2}$; (vi) $x, y + \frac{1}{2}, -z$.

Data collection: *CrysAlis CCD* (Oxford Diffraction, 2006); cell refinement: *CrysAlis CCD*; data reduction: *CrysAlis RED* (Oxford Diffraction, 2006); program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *DIAMOND* (Brandenburg, 1999); software used to prepare material for publication: *WinGX* (Farrugia, 1999) and *enCIFer* (Allen *et al.*, 2004).

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: BR2113).

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supplementary materials

Acta Cryst. (2009). E65, i67 [doi:10.1107/S160053680903147X]

Cs₂Bi(PO₄)(WO₄)

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Comment

Chemistry of caesium phosphates shows a great diversity due to its structural flexibility in adopting different coordination environment. In metal phosphates caesium resides generally in complex polyhedron with up to fourteen vertices providing formation of two- and three-dimensional frameworks. Depending on crystal structure caesium is believed to occupy big cavities and tunnels adapting their geometry. For instance, the structure of $Cs_3Mo_8O_{11}(PO_4)_8$ (Borel *et al.*, 2000) represents two types of irregular surrounding with nine and ten oxygen coordination, $Cs_2Ti(VO_2)_3(PO_4)_3$ (Yakubovich *et al.*,2006) - twelve and fourteen. Herein, the structure of $K_2Bi(PO_4)(WO_4)$ (Zatovsky *et al.*, 2006) represents an interesting host for substitution of potassium atoms by caesium ones, that leads to formation of the first example of caesium-containing phosphate-tungstate $Cs_2Bi(PO_4)(WO_4)$ (Fig 1). Three-dimensional framework of the title compound is organized by linking together [Bi(PO_4)(WO_4)] nets which are formed by adhesion [BiPO_4] layers and WO_4 tetrahedra above and below of those layers (Fig. 2). Both phosphate and tungstate tetrahedra have almost regular geometry with typical bond lengths. Caesium atom resides in interlayer space having eightfold coordination duplicating potassium ones' environment in the structure of $K_2Bi(PO_4)(WO_4)$ (Zatovsky *et al.*, 2006). Due to bigger ionic radius of Cs, the distance between two successive nets (a half of a cell dimension a) is 10.657 Å, while for K-analogue is 9.862 Å.

Experimental

Single crystals of the title compound were obtained during investigation in the pseudo-quaternary molten system Cs_2O — Bi_2O_3 — P_2O_5 — WO_3 . A mixture of $CsPO_3$ (1.060 g), $Cs_2W_2O_7$ (3.725 g) and Bi_2O_3 (0.840 g) were mixed in an agate mortar, and heated in a platinum crucible up to 1223 K to obtain a homogeneous melt. It was held at this temperature for an hour and cooled down with a rate of 40 K h⁻¹ to 833 K. Crystalline product was leached out from the solidified melt with hot water.

Refinement

Convergence factors (R, wR) and R_{int} are high due to low intensity of the reflections which is connected with poor quality of crystals. Experiments were carried out for several crystals from different synthetic points, unfortunately, better results than is presented were not found. Taking into account the previous structures isotypic to titled compound there is no doubts in structure determination.

The highest peak and the deepest hole in the final difference map are located at 0.77Å from P1 (2.173 e/Å³) and 0.70Å from P2 (-2.633 e/Å³) respectively.

Figures

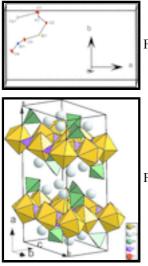


Fig. 1. View of the title compound with displacement ellipsoids at the 50% probability level.

Fig. 2. View of $Cs_2Bi(PO_4)(WO_4)$.

Dicaesium bismuth(III) phosphate(V) tungstate(VI)

Crystal a	lata
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Cs ₂ Bi(PO ₄)(WO ₄)	$F_{000} = 2768$
$M_r = 817.61$	$D_{\rm x} = 5.648 {\rm ~Mg~m}^{-3}$
Orthorhombic, Ibca	Mo K α radiation, $\lambda = 0.71073$ Å
Hall symbol: -I 2b 2c	Cell parameters from 10697 reflections
a = 21.3144 (10) Å	$\theta = 3.2 - 30.0^{\circ}$
<i>b</i> = 12.6352 (5) Å	$\mu = 37.87 \text{ mm}^{-1}$
c = 7.1412 (3) Å	T = 293 K
$V = 1923.21 (14) \text{ Å}^3$	Prism, colourless
<i>Z</i> = 8	$0.08\times0.07\times0.05~mm$

Data collection

Oxford Diffraction XCalibur-3 diffractometer	1396 independent reflections
Radiation source: fine-focus sealed tube	1227 reflections with $I > 2\sigma(I)$
Monochromator: graphite	$R_{\rm int} = 0.156$
T = 293 K	$\theta_{\text{max}} = 30.0^{\circ}$
ϕ and ω scans	$\theta_{\min} = 3.2^{\circ}$
Absorption correction: multi-scan (Blessing, 1995)	$h = -27 \rightarrow 29$
$T_{\min} = 0.061, T_{\max} = 0.174$	$k = -17 \rightarrow 17$
10697 measured reflections	$l = -10 \rightarrow 10$

Refinement

Refinement on F^2	Primary atom site location: structure-invariant direct methods
Least-squares matrix: full	Secondary atom site location: difference Fourier map
$R[F^2 > 2\sigma(F^2)] = 0.052$	$w = 1/[\sigma^2(F_o^2) + (0.0396P)^2 + 22.3992P]$ where $P = (F_o^2 + 2F_c^2)/3$
$wR(F^2) = 0.115$	$(\Delta/\sigma)_{\rm max} < 0.001$
<i>S</i> = 1.21	$\Delta \rho_{max} = 2.17 \text{ e } \text{\AA}^{-3}$
1396 reflections	$\Delta \rho_{\rm min} = -2.63 \text{ e } \text{\AA}^{-3}$
61 parameters	Extinction correction: none

Special details

Geometry. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted *R*-factor *wR* and goodness of fit *S* are based on F^2 , conventional *R*-factors *R* are based on *F*, with *F* set to zero for negative F^2 . The threshold expression of $F^2 > \sigma(F^2)$ is used only for calculating *R*-factors(gt) *etc.* and is not relevant to the choice of reflections for refinement. *R*-factors based on F^2 are statistically about twice as large as those based on *F*, and *R*- factors based on ALL data will be even larger.

	x	У	Z	$U_{\rm iso}$ */ $U_{\rm eq}$
Bi1	0.25	0.58662 (4)	0	0.01381 (17)
Cs1	0.09029 (3)	0.83471 (6)	0.21999 (11)	0.0233 (2)
W1	0.09279 (3)	0.5	0.25	0.01566 (18)
P1	0.25	0.8232 (3)	0	0.0081 (6)
01	0.2413 (4)	0.8984 (6)	0.1675 (11)	0.0204 (17)
02	0.3072 (4)	0.7487 (6)	0.0220 (11)	0.0173 (15)
O3	0.1403 (4)	0.5328 (8)	0.0513 (13)	0.0258 (18)
O4	0.0440 (4)	0.3925 (8)	0.1847 (13)	0.031 (2)

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (A^2)

Atomic displacement parameters (A^2)						
	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
Bi1	0.0116 (3)	0.0135 (3)	0.0162 (3)	0	-0.00033 (18)	0
Cs1	0.0166 (4)	0.0290 (4)	0.0243 (4)	0.0014 (3)	-0.0003 (2)	0.0005 (3)
W1	0.0107 (3)	0.0162 (3)	0.0201 (3)	0	0	0.0007 (2)
P1	0.0077 (15)	0.0086 (13)	0.0080 (15)	0	-0.0014 (10)	0
01	0.034 (5)	0.015 (3)	0.012 (4)	-0.004 (3)	0.002 (3)	-0.003 (3)
O2	0.013 (4)	0.017 (3)	0.021 (4)	-0.001 (3)	0.000 (3)	0.003 (3)
03	0.013 (4)	0.036 (5)	0.028 (4)	-0.007 (4)	-0.004 (3)	0.006 (4)
O4	0.020 (5)	0.032 (5)	0.040 (5)	-0.013 (4)	0.007 (4)	-0.013 (4)

Geometric parameters (Å, °)

Bi1—O2	2.388 (8)	Cs1—O4 ^{viii}	3.111 (10)
Bi1—O2 ⁱ	2.388 (8)	Cs1—O4 ^{ix}	3.140 (9)
Bi1—O1 ⁱⁱ	2.389 (8)	Cs1—O1	3.338 (9)
Bi1—O1 ⁱⁱⁱ	2.389 (8)	Cs1—O3 ^{ix}	3.339 (9)
Bi1—O3 ⁱ	2.463 (8)	W1—O4	1.774 (9)
Bi1—O3	2.463 (8)	W1—O4 ^{viii}	1.774 (9)
Bi1—O1 ^{iv}	2.669 (8)	W1—O3 ^{viii}	1.792 (9)
Bi1—O1 ^v	2.669 (8)	W1—O3	1.792 (9)
Cs1—O2 ⁱ	2.990 (8)	P1—O1	1.539 (8)
Cs1—O4 ^{vi}	3.031 (9)	P1—O1 ⁱ	1.539 (8)
Cs1—O2 ⁱⁱ	3.046 (8)	P1—O2 ⁱ	1.549 (8)
Cs1—O3 ^{vii}	3.088 (9)	P1—O2	1.549 (8)
?—?—?	?		

Symmetry codes: (i) -*x*+1/2, *y*, -*z*; (ii) -*x*+1/2, -*y*+3/2, -*z*+1/2; (iii) *x*, -*y*+3/2, *z*-1/2; (iv) *x*, *y*-1/2, -*z*; (v) -*x*+1/2, *y*-1/2, *z*; (vi) -*x*, *y*+1/2, -*z*+1/2; (vii) *x*, -*y*+3/2, *z*+1/2; (viii) *x*, -*y*+1/2, -*z*.



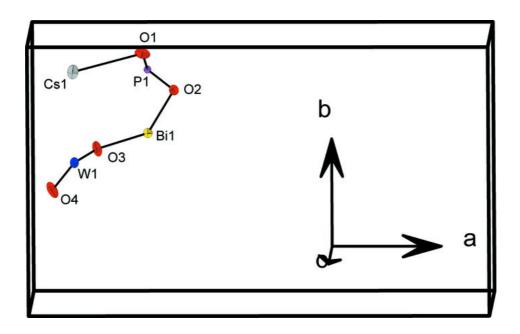


Fig. 2

